12-bit Address Comparator

HITACHI

Description

The HD74HC679 address comparator simplifies addressing of memory boards and/or other peripheral devices. The four P inputs are normally hard wired with a preprogrammed address. An internal decoder determines what input information applied to the 12 A inputs must be low or high to cause a low state at the output (Y). For example, a positive-logic bit combination of 0111 (decimal 7) at the P input determines that inputs A_1 through A_7 must be low and that inputs A_8 through A_{12} must be high to cause the output to go low. Equality of the address amplified at the A inputs to the preprogrammed address is indicated by the output being low.

The HD74HC679 features and enable input (\overline{G}) . When \overline{G} is low, the device is enabled. When \overline{G} is high, the device is disabled and the output is high regardless of the A and P inputs.

Features

• High Speed Operation: t_{pd} (A to Y) = 18 ns typ ($C_L = 50 \text{ pF}$)

• High Output Current: Fanout of 10 LSTTL Loads

• Wide Operating Voltage: $V_{CC} = 2$ to 6 V

Low Input Current: 1 μA max

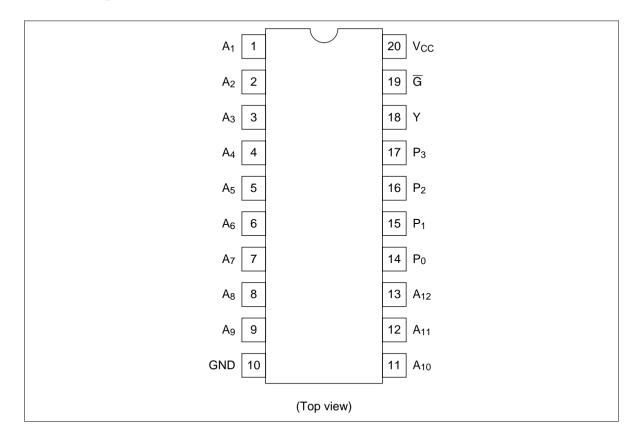
• Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max (Ta = 25°C)



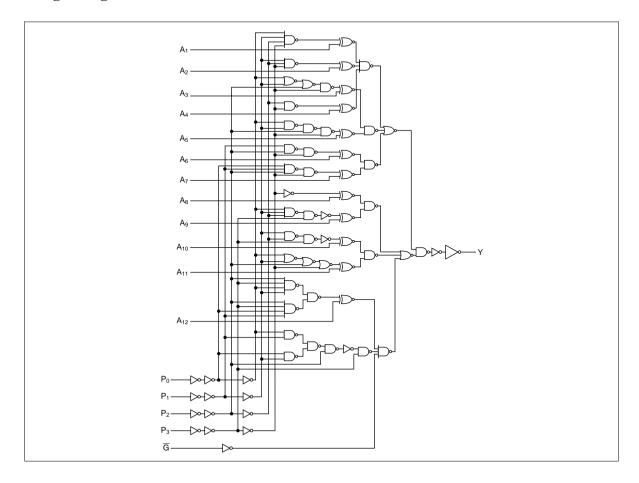
Function Table

	Inputs																
$\overline{\mathbf{G}}$	P ₃	P ₂	P ₁	Po	A ₁	A ₂	A_3	A_4	A_5	A_6	A ₇	A ₈	A ₉	A ₁₀	A ₁₁	A ₁₂	Output Y
L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L
L	L	L	L	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L
L	L	L	Н	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L
L	L	L	Н	Н	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	L
L	L	Н	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	L
L	L	Н	L	Н	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	L
L	L	Н	Н	L	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	L
L	L	Н	Н	Н	L	L	L	L	L	L	L	Н	Н	Н	Н	Н	L
L	Н	L	L	L	L	L	L	L	L	L	L	L	Н	Н	Н	Н	L
L	Н	L	L	Н	L	L	L	L	L	L	L	L	L	Н	Н	Н	L
L	Н	L	Н	L	L	L	L	L	L	L	L	L	L	L	Н	Н	L
L	Н	L	Н	Н	L	L	L	L	L	L	L	L	L	L	L	Н	L
L	Н	Н	L	L	L	L	L	L	L	L	L	L	L	L	L	L	L
L	Н	Н	L	Н	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Н
L	Н	Н	Н	L	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Х	Н
L	Н	Н	Н	Н	L	L	L	L	L	L	L	L	L	L	L	L	L
L	All other combinations											Н					
Н	Any combination											Н					

Pin Arrangement



Logic Diagram



DC Characteristics

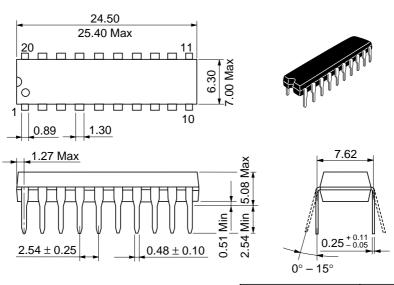
			Ta =	= 25°(Ta = - +85°C	-40 to			
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions	
Input voltage	V _{IH}	2.0	1.5	_	_	1.5	_	V		
		4.5	3.15	i —	_	3.15	_	=		
		6.0	4.2	_	_	4.2	_	=		
	V _{IL}	2.0	_	_	0.5	_	0.5	V		
		4.5	_	_	1.35	_	1.35	_		
		6.0	_	_	1.8	_	1.8	=		
Output voltage	V _{OH}	2.0	1.9	2.0		1.9	_	V	Vin = V_{IH} or V_{IL} $I_{OH} = -20 \mu$	ιΑ
		4.5	4.4	4.5	_	4.4	_	_		
		6.0	5.9	6.0	_	5.9	_	=		
		4.5	4.18	3 —		4.13	_	_	$I_{OH} = -4 \text{ m}.$	Α
		6.0	5.68	3 —	_	5.63	_	=	$I_{OH} = -5.2$	mA
	V _{OL}	2.0	_	0.0	0.1	_	0.1	V	$Vin = V_{IH} \text{ or } V_{IL} I_{OL} = 20 \mu A$	١
		4.5	_	0.0	0.1	_	0.1	_		
		6.0	_	0.0	0.1	_	0.1	_		
		4.5	_	_	0.26	_	0.33	=	$I_{OL} = 4 \text{ mA}$	
		6.0	_	_	0.26	_	0.33	_	$I_{OL} = 5.2 \text{ m}$	Α
Input current	lin	6.0	_	_	±0.1	_	±1.0	μΑ	Vin = V _{CC} or GND	
Quiescent supply current	I _{cc}	6.0	_	_	4.0	_	40	μΑ	$Vin = V_{CC}$ or GND, lout = 0	μΑ

AC Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

	Ta = -40 to
Ta = 25°C	+85°C

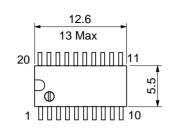
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Propagation delay	t _{PLH}	2.0	_	_	310	_	390	ns	P to Y
time	$t_{\tiny PHL}$	4.5	_	27	62	_	78	_	
		6.0	_	_	52	_	66		
	t_{PLH}	2.0	_	_	180	_	225	ns	A to Y
	$t_{\tiny PHL}$	4.5	_	18	36	_	45		
		6.0	_	_	31	_	38	_	
	t _{PLH}	2.0	_	_	125	_	155	ns	G to Y
	$t_{\tiny PHL}$	4.5	_	14	25	_	31	_	
		6.0	_	_	21	_	26	_	
Output rise/fall	t _{TLH}	2.0	_	_	75	_	95	ns	
time	t_{THL}	4.5	_	5	15	_	19	_	
		6.0	_	_	13	_	16	=	
Input capacitance	Cin	_	_	5	10	_	10	pF	

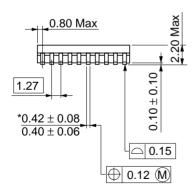
Unit: mm

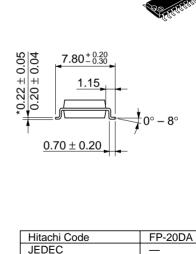


Hitachi Code	DP-20N
JEDEC	_
EIAJ	Conforms
Weight (reference value)	1.26 g

Unit: mm







Weight (reference value)

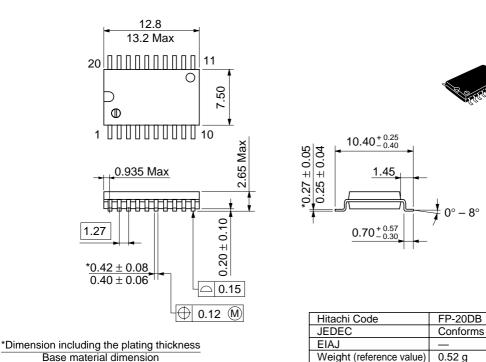
Conforms

0.31 g

EIAJ

*Dimension including the plating thickness
Base material dimension

Unit: mm



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